

Low VF SMD Schottky Barrier Rectifiers

COMCHIP
SMD Diodes Specialist

CDBA320L-G Thru. CDBA340L-G

Reverse Voltage: 20 to 40 Volts

Forward Current: 3.0 Amp

RoHS Device

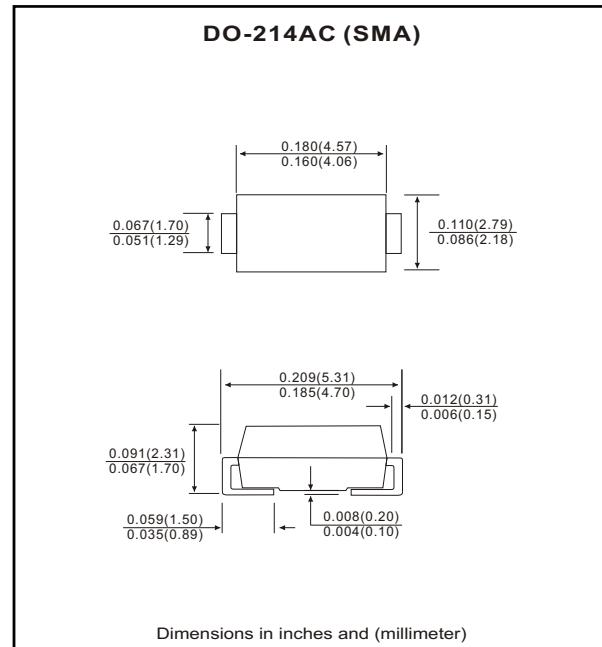


Features

- Ideal for surface mount applications.
- Easy pick and place.
- Plastic package has Underwriters Lab. flammability classification 94V-0.
- Built in strain relief.
- Super low forward voltage drop.

Mechanical data

- Case: JEDEC DO-214AC, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Polarity: Color band denotes cathode end.
- Approx. weight: 0.064 grams



Maximum Ratings and Electrical Characteristics

Single phase half wave, 60Hz, resistive or inductive load. For Capacitive load, derate current by 20%.

Parameter	Symbol	CDBA320L-G	CDBA340L-G	Units
Max. repetitive peak reverse voltage	V _{RRM}	20	40	V
Max. DC blocking voltage	V _{DC}	20	40	V
Max. RMS voltage	V _{RMS}	14	28	V
Peak surge forward current, 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}	80		
Max. average forward current	I _o	3.0		
Max. instantaneous forward voltage at 3.0A	V _F	0.38	0.40	V
Max. DC reverse current at T _A =25°C rated DC blocking voltage T _A =80°C	I _R	1.5 60		mA
Max. thermal resistance (Note 1)	R _{θJA} R _{θJL}	88 20		°C/W
Max. operating junction temperature	T _J	125		
Storage temperature	T _{STG}	-50 to +150		

Notes: 1. Thermal resistance from junction to ambient and junction to lead, P.C.B. mounted on 0.2×0.2 inch² copper pad area.

REV:A

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RATING AND CHARACTERISTIC CURVES (CDBA320L-G thru CDBA340L-G)

Fig.1 Reverse Characteristics

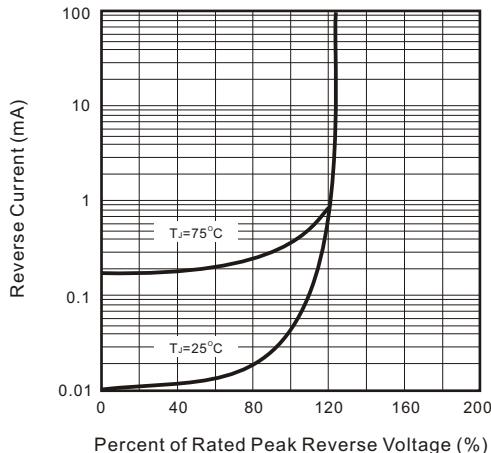


Fig.2 Forward Characteristics

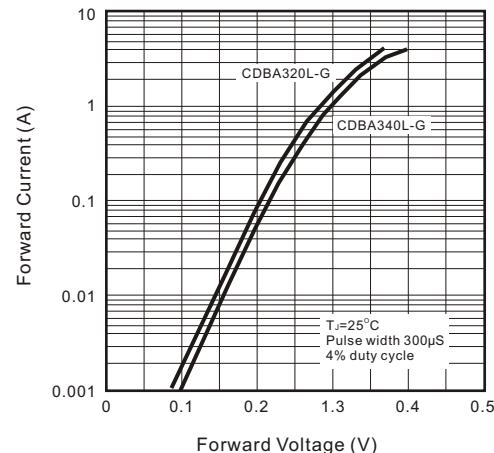


Fig.3 Junction Capacitance

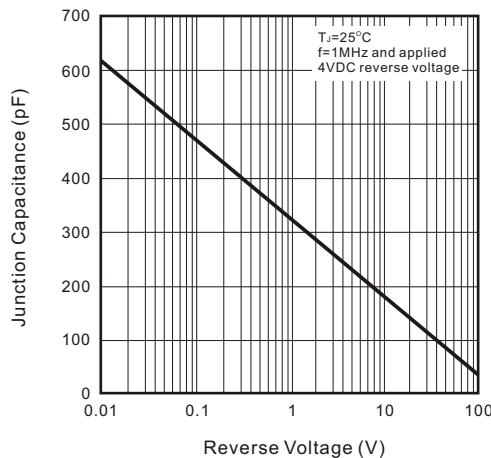


Fig.4 Current Derating Curve

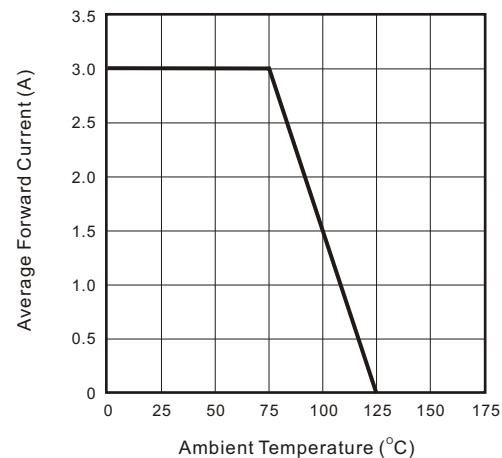


Fig.5 Non-repetitive Forward Surge Current

